

# PUMX1

# 40 V, 100 mA NPN/NPN general-purpose transistor Rev. 04 — 20 January 2010 Produ

**Product data sheet** 

#### 1. **Product profile**

## 1.1 General description

NPN/NPN general-purpose transistor with two independently operating transistors in a SOT363 (SC-88) very small Surface-Mounted Device (SMD) plastic package.

Table 1. **Product overview** 

Type number	Package	PNP/PNP		NPN/PNP	
	NXP	JEITA	complement	complement	
PUMX1	SOT363	SC-88	PUMT1	PUMZ1	

#### 1.2 Features

- Double general-purpose transistor
- Board-space reduction
- Very small SMD plastic package

## 1.3 Applications

General-purpose switching and amplification

#### **Pinning information** 2.

Dinning Table 2

Table 2.	Filling		
Pin	Description	Simplified outline	Graphic symbol
1	emitter TR1		
2	base TR1	6 5 4	6 5 4
3	collector TR2		TR2
4	emitter TR2	0	(TR1)
5	base TR2	□1 □2 □3	
6	collector TR1		1 2 3
			sym020



## 40 V, 100 mA NPN general-purpose double transistor

# 3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PUMX1	SC-88	plastic surface-mounted package; 6 leads	SOT363		

# 4. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMX1	<b>Z*Z</b>

<sup>[1] \* = -:</sup> made in Hong Kong

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
Per transistor						
$V_{CBO}$	collector-base voltage	open emitter	-	50	V	
$V_{CEO}$	collector-emitter voltage	open base	-	40	V	
$V_{EBO}$	emitter-base voltage	open collector	-	5	V	
I <sub>C</sub>	collector current		-	100	mA	
I <sub>CM</sub>	peak collector current		-	200	mA	
I <sub>BM</sub>	peak base current		-	200	mA	
P <sub>tot</sub>	total power dissipation	$T_{amb} \leq 25~^{\circ}C$	-	200	mW	
Per device	)					
P <sub>tot</sub>	total power dissipation	$T_{amb} \leq 25~^{\circ}C$	<u>[1]</u> _	300	mW	
T <sub>j</sub>	junction temperature		-	150	°C	
$T_{amb}$	ambient temperature		-65	+150	°C	
T <sub>stg</sub>	storage temperature		-65	+150	°C	

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

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# 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device	•					
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	416	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

# 7. Characteristics

Table 7. Characteristics

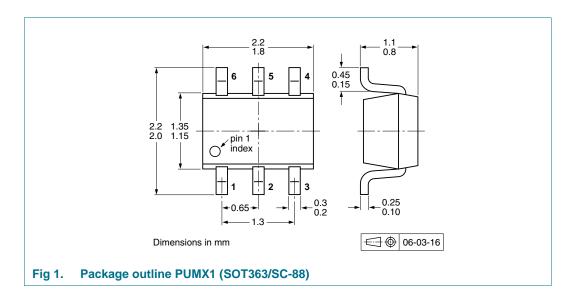
 $T_{amb} = 25$  °C unless otherwise specified.

· arrib = 0	o amoso carormos opcomosar					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transi	stor					
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 30 \text{ V};$ $I_{E} = 0 \text{ A}$	-	-	100	nA
		$V_{CB} = 30 \text{ V};$ $I_{E} = 0 \text{ A};$ $T_{j} = 150 \text{ °C}$	-	-	10	μА
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 4 V;$ $I_C = 0 A$	-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = 6 V;$ $I_{C} = 1 \text{ mA}$	120	-	-	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 50 \text{ mA};$ $I_B = 5 \text{ mA}$	<u>[1]</u> _	-	200	mV
f <sub>T</sub>	transition frequency	$I_C = 2 \text{ mA};$ $V_{CE} = 12 \text{ V};$ f = 100  MHz	100	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 12 \text{ V};$ $I_E = i_e = 0 \text{ A};$ $f = 1 \text{ MHz}$	-	-	1.5	pF

<sup>[1]</sup> Pulse test:  $t_p \leq 300~\mu s;~\delta \leq 0.02.$ 

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# 8. Package outline



# 9. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type Package Description			Packing quantity		
number				3000	10000
PUMX1 SOT363		4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165

<sup>[1]</sup> For further information and the availability of packing methods, see Section 12.

[2] T1: normal taping

[3] T2: reverse taping



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# 10. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
PUMX1_4	20100120	Product data sheet	-	PUMX1_3	
Modifications:		f this data sheet has been rec NXP Semiconductors.	lesigned to comply w	rith the new identity	
	<ul> <li>Legal texts h</li> </ul>	ave been adapted to the new	company name whe	re appropriate.	
	• Table 1 "Prod	duct overview": added			
	<ul> <li>Section 1.2 "</li> </ul>	Features": updated			
	<ul> <li>Section 1.3 ".</li> </ul>	Applications": amended			
	Section 2 "Pinning information": amended				
	• Figure 1: superseded by minimized package outline drawing				
	Section 9 "Packing information": added				
	Section 11 "L	egal information": updated			
PUMX1_3	19990414	Preliminary specification	-	PUMX1_2	
PUMX1_2	19970709	Preliminary specification	-	PUMX1_1	
-					

#### 40 V, 100 mA NPN general-purpose double transistor

# 11. Legal information

#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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## 40 V, 100 mA NPN general-purpose double transistor

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